

# 2A / 30V Bipolar transistor

## 2SD2679

### ●Applications

Low frequency amplification, driver

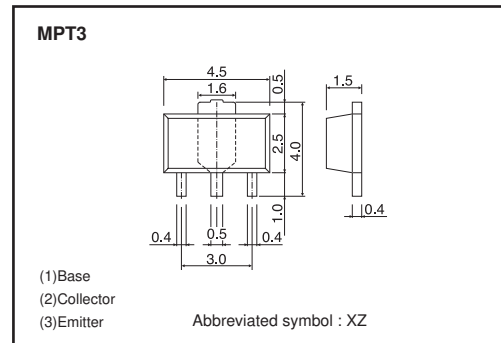
### ●Features

- 1) Collector current is high.
- 2) Low collector-emitter saturation voltage.  
( $V_{CE(sat)} \leq 350\text{mV}$  at  $I_C = 1.5\text{A}$ ,  $I_B = 75\text{mA}$ )

### ●Structure

NPN epitaxial planar silicon transistor

### ●Dimensions (Unit : mm)



### ●Absolute maximum ratings ( $T_a=25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CBO}$	30	V
Collector-emitter voltage	$V_{CEO}$	30	V
Emitter-base voltage	$V_{EBO}$	6	V
Collector current	DC	$I_C$	2
	Pulse	$I_{CP}$	4 *1
Power dissipation	$P_C$	0.5 *2	W
		2 *3	
Junction temperature	$t_j$	150	$^\circ\text{C}$
Storage temperature	$t_{stg}$	-55 to +150	$^\circ\text{C}$

\*1  $P_w=1\text{ms}$ , single pulse.

\*2 Each terminal mounted on a recommended land.

\*3 Mounted on a  $40 \times 40 \times 0.7\text{mm}$  ceramic board.

### ●Packaging specifications

Part No.	Package	MPT3
2SD2679	Packaging type	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
		○

### ●Electrical characteristics ( $T_a=25^\circ\text{C}$ )

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	$BV_{CEO}$	30	-	-	V	$I_C=1\text{mA}$
Collector-base breakdown voltage	$BV_{CBO}$	30	-	-		$I_C=10\mu\text{A}$
Emitter-base breakdown voltage	$BV_{EBO}$	6	-	-		$I_E=10\mu\text{A}$
Collector cut-off current	$I_{CBO}$	-	-	100	nA	$V_{CB}=30\text{V}$
Emitter cut-off current	$I_{EBO}$	-	-	100		$V_{EB}=6\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$ *	-	180	370	mV	$I_C/I_B=1.5\text{A}/75\text{mA}$
DC current gain	$h_{FE}$	270	-	680	-	$V_{CE}=2\text{V}$ , $I_C=200\text{mA}$
Transition frequency	$f_T$	-	280	-	MHz	$V_{CE}=2\text{V}$ , $I_E=-200\text{mA}$ , $f=100\text{MHz}$
Collector output capacitance	$C_{ob}$	-	20	-	pF	$V_{CB}=10\text{V}$ , $I_E=0\text{mA}$ , $f=1\text{MHz}$

\* Pulsed

Transistors

●Electrical characteristics curves

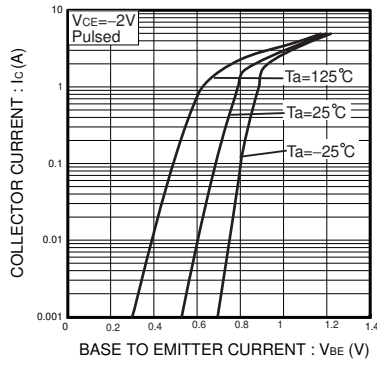


Fig.1 Grounded emitter propagation characteristics

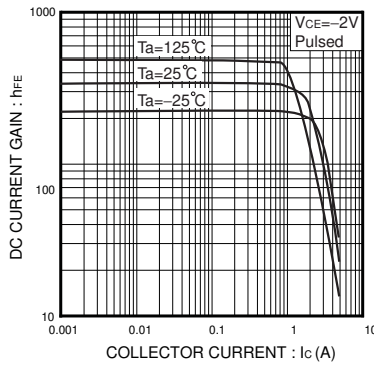


Fig.2 DC current gain vs. collector current

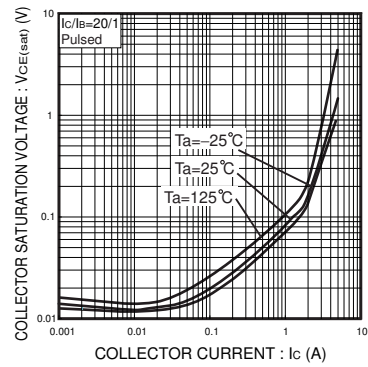


Fig.3 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

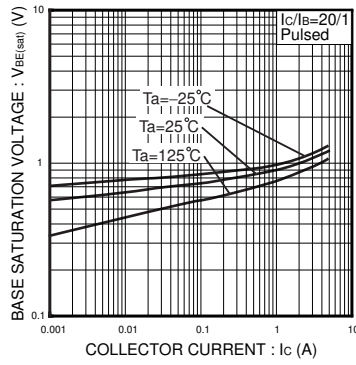


Fig.4 Base-emitter saturation voltage vs. collector current

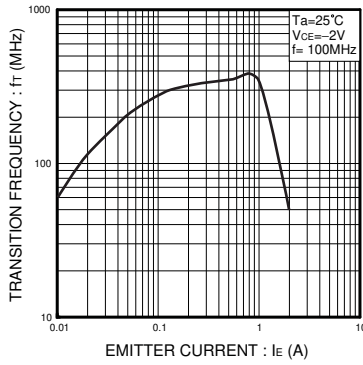


Fig.5 Gain bandwidth product vs. emitter current

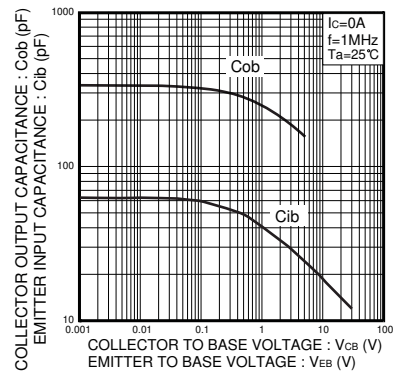


Fig.6 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

### Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

It is our top priority to supply products with the utmost quality and reliability. However, there is always a chance of failure due to unexpected factors. Therefore, please take into account the derating characteristics and allow for sufficient safety features, such as extra margin, anti-flammability, and fail-safe measures when designing in order to prevent possible accidents that may result in bodily harm or fire caused by component failure. ROHM cannot be held responsible for any damages arising from the use of the products under conditions out of the range of the specifications or due to non-compliance with the NOTES specified in this catalog.

Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact your nearest sales office.

**ROHM** Customer Support System

THE AMERICAS / EUROPE / ASIA / JAPAN

[www.rohm.com](http://www.rohm.com)

Contact us : [webmaster@rohm.co.jp](mailto:webmaster@rohm.co.jp)